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ECE - A

Physics: Electromagnetic
Theory, Quantum
Mechanics, Waves and
Optics- 18PYB101J

TO STUDY THE V-I CHARACTERISTICS OF A LIGHT DEPENDENT RESISTORCLOR)

AIM:

04.06.2021

To measure the photo conductive naturate and the dark residence of the given light dependent tesistor (LDR) and to plot the Characteristics of the LDR.

APPARATUS RECUIRED:

LDR, Resistor (1 KD), ammeter (0-10 mA), voltmeter (0-10 V), light Source, regulated hower Jupply.

FORMULA:

By Ohm's Law, V= IR (a) R= V/I ohm.

Whore K is the resistance of the LDR Circ) the resistance when the LDR is Closed. Vand I telephosening the Corresponding Voltage and Correct telpectively.

PRINCIPLE:

The photoconductive device is based on the decrease in the resistance of Certain Lemiconductor materials when they are exposed to both influenced and Visible tadiation. The photoconductivity is the result of Carrier excitation due to eight absorption and the discre of Metit depends on the eight absorption elliciency. The increase in Conductivity is fee to

Ang Rr = 0.34 kn

an increase in the number of mobile charge Carriers in the material OBSERVATION: Distance at 15 cm, 10 cm and 8 cm.

CALCULATION:

For d= 15 cm. ; R = V/I. 1. RR= 1/4×10-3 = 250 A or 0.25 K.A.

2. Rr = 0.33 ks 3- Ra= 3/10 = 0.3 LA

4. RR = 4/12 = 0.33 km 5. Rr = 0.36 ks

Fa d = 10 cm,

1. Re= 0.125 due

Aug RR= 0:177 RR

2. RR = 0.166 R.A

3. Rr = 3/16 mA = 0.187 ks

4. fr = 4/20mA = 0.2 ks

F. Ra = 5/24 mA = 0.208 kA

For d= 5 cm,

1. RR = 1/10 MA = 0.1 k.2

Aug Rr = 0.152 ks

2. PR = 2/14 MA = 0.143 K.A.

3. RR = 3/18 mA = 0.166 k. A

4. Rr = 4 /23 MA= 0.174 k.s.

5. Rr = 5/28 mA = 0.179 k.s.

Mean Rr = 0:314 + 0:171 + 0:152 = 0.214.

RESULT:

- (i) The Characteristics of LDR were Studied and plotted.
- (ii) The durk resistance of the given LDR= 0.214. Rohm.



